

BAT74

Schottky barrier double diode Rev. 03 — 19 April 2010

Product data sheet

Product profile

1.1 General description

Planar Schottky barrier double diode with an integrated guard ring for stress protection. Two electrically isolated Schottky barrier diodes, encapsulated in a small SOT143B Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Low forward voltage
- Guard-ring protected
- Small SMD plastic package

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Blocking diodes

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		-	-	200	mA
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	$I_F = 100 \text{ mA}$	-	-	800	mV

Pinning information 2.

Table 2. **Pinning**

Idbio L.	1 11111119		
Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	4 3	4 3
3	anode (diode 2)		
4	anode (diode 1)	1 2	1 2 006aaa434



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3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BAT74	-	plastic surface-mounted package; 4 leads	SOT143B	

4. Marking

Table 4. Marking codes

Type number	Marking code[1]
BAT74	*L4

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	reverse voltage		-	30	V
I _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \leq \text{1 s; } \delta \leq 0.5$	-	300	mA
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms	-	600	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	-	230	mW
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		-65	+125	°C
T _{stg}	storage temperature		-65	+150	°C
Double di	ode operation				
V_R	reverse voltage		-	30	V
			[1] -	60	V
I _F	forward current		[2] _	110	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ s; } \delta \leq 0.5$	-	200	mA

^[1] Series connection.

^[2] If both diodes are in forward operation at the same moment, total device current is max. 110 mA. If one diode is in reverse operation and the other is in forward operation at the same moment, total device current is max. 200 mA.

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6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W

^[1] Refer to SOT143B standard mounting conditions.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

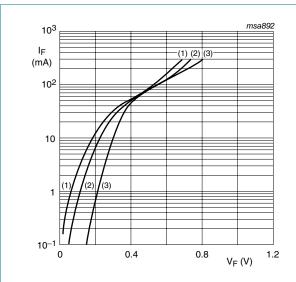
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V _F	forward voltage	$I_F = 0.1 \text{ mA}$	-	-	240	mV
		I _F = 1 mA	<u>[1]</u> -	-	320	mV
		I _F = 10 mA	-	-	400	mV
		I _F = 30 mA	-	-	500	mV
		I _F = 100 mA	-	-	800	mV
I _R	reverse current	V _R = 25 V	[2] _	-	2	μΑ
C _d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$	-	-	10	pF
t _{rr}	reverse recovery time		[3] -	-	5	ns

^[1] Temperature coefficient of forward voltage -0.6 %/K.

^[2] Pulse test: $t_p = 300 \ \mu s; \ \delta = 0.02.$

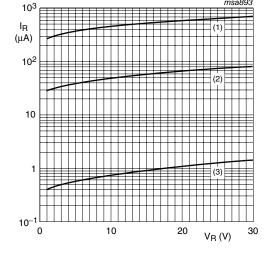
^[3] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

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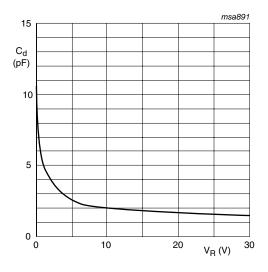
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



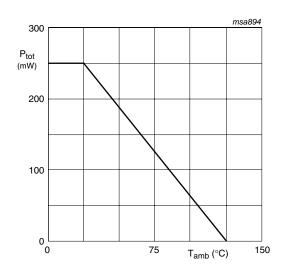
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values



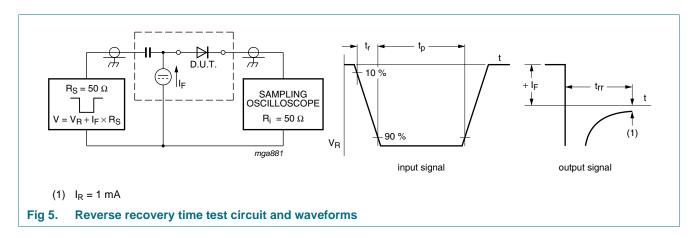
Standard footprint

Fig 4. Power derating curve

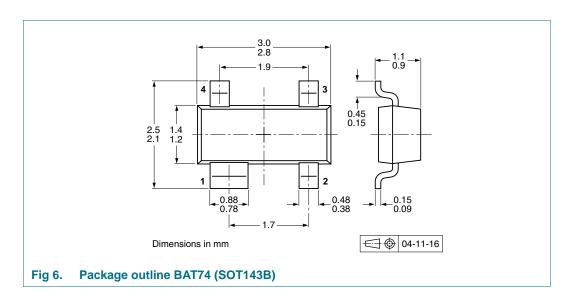
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8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

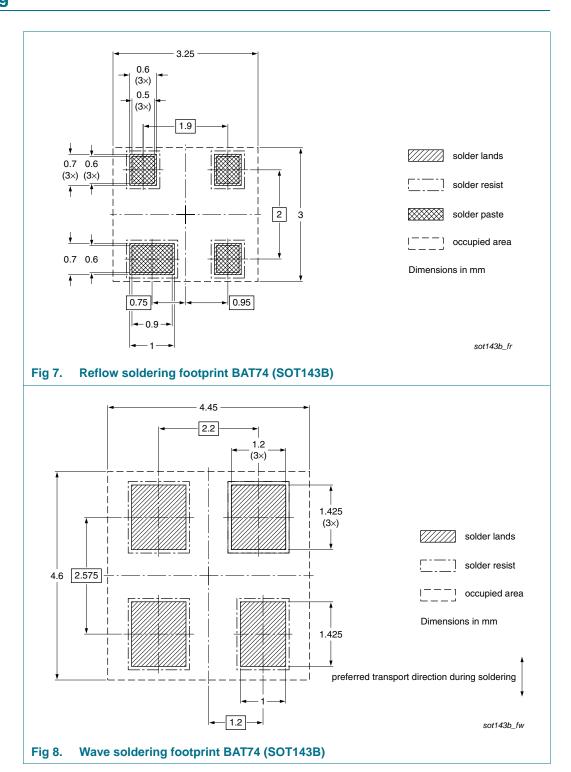
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
BAT74	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235

^[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BAT74_3	20100419	Product data sheet	-	BAT74_2			
Modifications:		of this data sheet has been f NXP Semiconductors.	redesigned to comply	with the new identity			
	 Legal texts have been adapted to the new company name where appropriate. 						
	 Section 1.1 "General description": amended 						
	Table 1 "Quick reference data": added						
	Section 4 "Marking": updated						
	 Section 8 "Test information": added 						
	• Figure 5: enhanced						
	 Figure 6: superseded by minimized package outline drawing 						
	 Section 10 "Packing information": added 						
	Section 11 "Soldering": added						
	Section 13 "	Legal information": updated					
BAT74_2	20010905	Product specification	-	BAT74_1			
BAT74 1	19960319	Product specification					

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAT74_3

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